

Scaled Reduced Mode Sapphire Fiber Production (RMSF) Towards High Temperature Radiation Resilient Sensors

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Luna Innovations Overview



Luna focuses on developing advanced optical technology and solutions that enable our customers to more efficiently design, manufacture and manage products, processes and assets.

SENSING



Infrastructure, Energy,
Automotive, Aerospace

- Fiber optic sensing
- Terahertz gauging/imaging

PHOTONICS TEST & CONTROL



Telecom, Datacom, Aero/Defense

- Fiber optic test
- Component test
- Lasers, modules, components



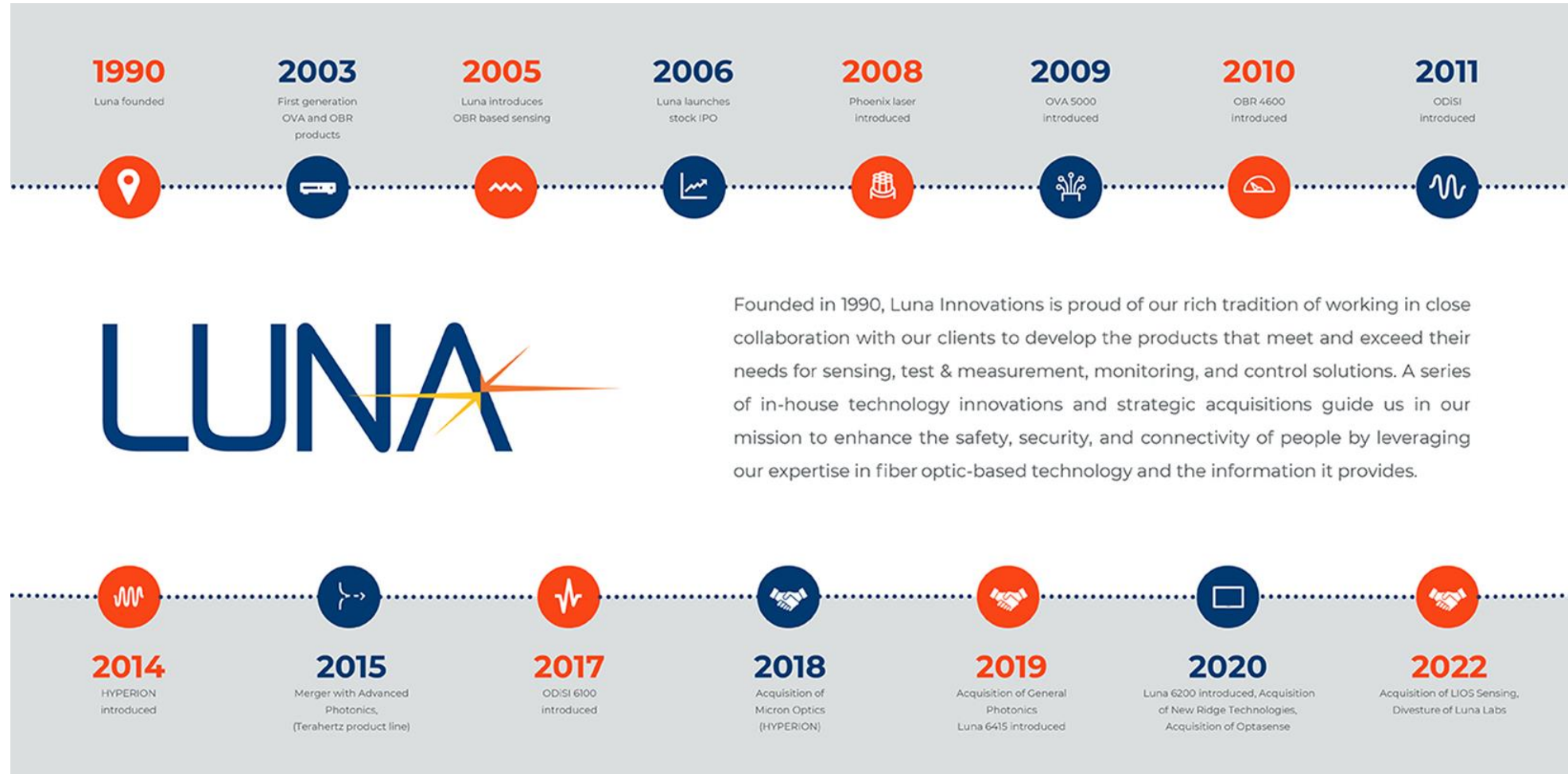
History
Incorporated 1990
IPO 2006



Employees
+400



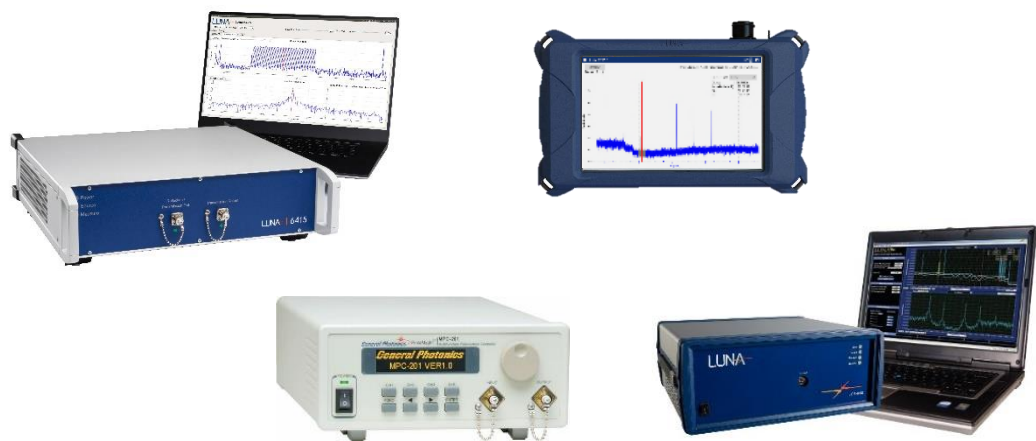
Luna has a clear vision and established history



Communications Test and Control — Product Portfolio

Test & Measurement

OEM Modules and Components



PIC / Component Test

Fiber Optic Network Test

Optical Backscatter Reflectometer (OBR)

Polarization Analysis

Polarization Management



Polarization Control

Tunable Filters





Delay/Phase Control

Tunable Lasers

Fiber Coils

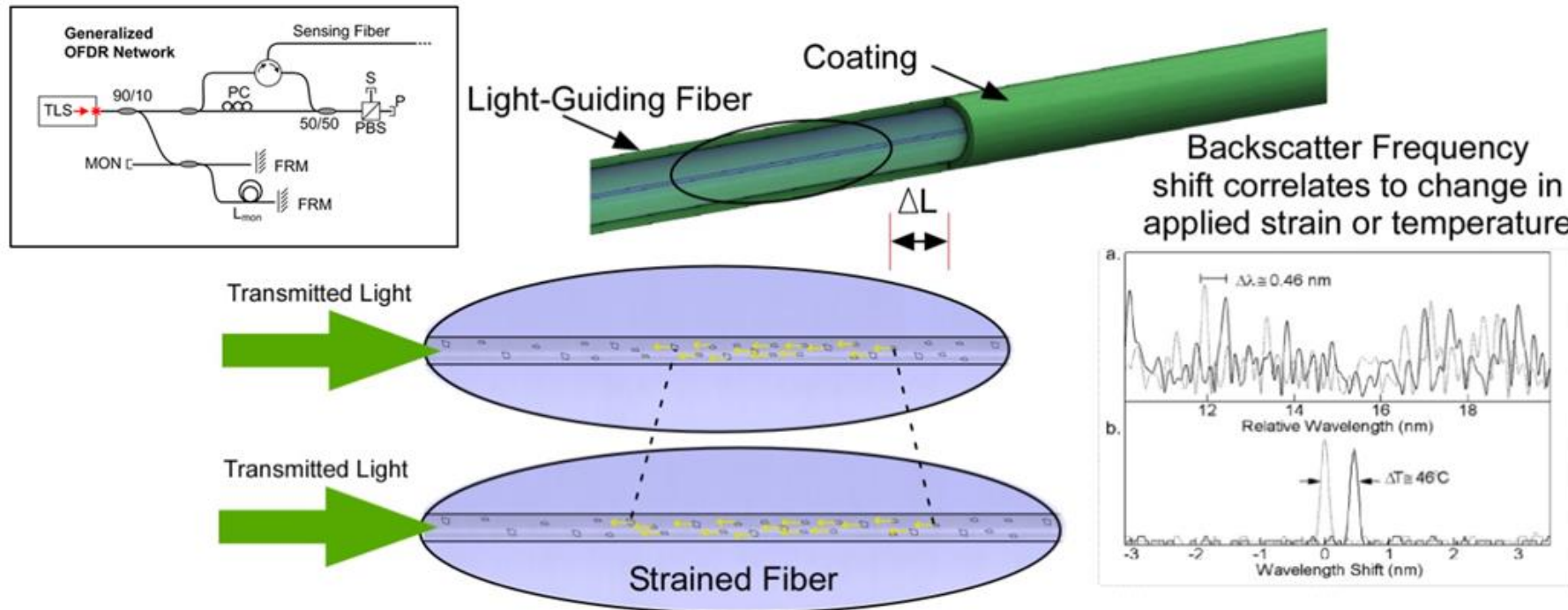
Narrow Linewidth Lasers

Fiber Optic Sensing: 4 Platforms, 4 Technologies

	High-Speed Multipoint	High-Definition Distributed	Distributed Acoustic Sensing	Distributed Acoustic Sensing
FOS Technology:	 <p>Fiber Bragg gratings (FBGs) and Fabry-Perot sensors</p>	 <p>Rayleigh backscatter <i>Optical Frequency Domain Reflectometry (OFDR)</i></p>	 <p>Rayleigh backscatter <i>Optical Time Domain Reflectometry (OTDR)</i></p>	 <p>Raman backscatter</p>
Point/Distributed:	Multipoint sensing	Distributed	Distributed	Distributed
Sensor/gage spacing:	FBG placement	Down to <1 mm	~1-10 m typical	0.25-10 m
Sensor fiber length:	Up to 10's of km's	100 m	Up to 50 - 100 km's	Up to 70 km
Measurements:	Strain, temperature, acceleration, displacement and pressure	Strain and temperature	Acoustics Strain, temperature	Strain and temperature
Example applications:	Civil infrastructure monitoring Aerospace condition monitoring Wind turbine monitoring	Battery thermal analysis Structural and material test Precision process monitoring	Pipelines Transportation/rail Perimeter security Oil and gas	Fire Detection Power cables Pipelines Transportation/rail Perimeter security Oil and gas

OFDR Distributed Sensing Overview

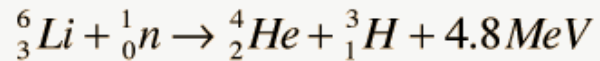
Optical Frequency Domain Reflectometry (OFDR), the basis of the ODiSI platform, uses reflected light from minute differences in the local index of refraction of the fiber core to determine the degree to which the fiber is strained as a result of a thermal or mechanical stimuli.



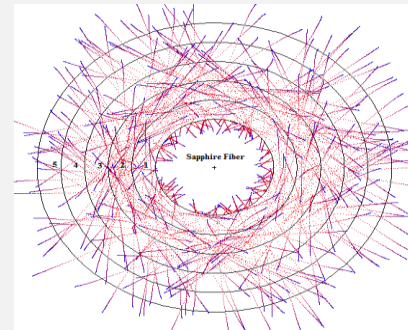
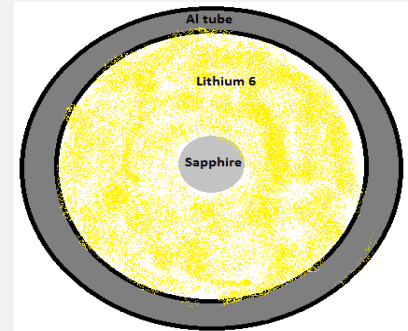
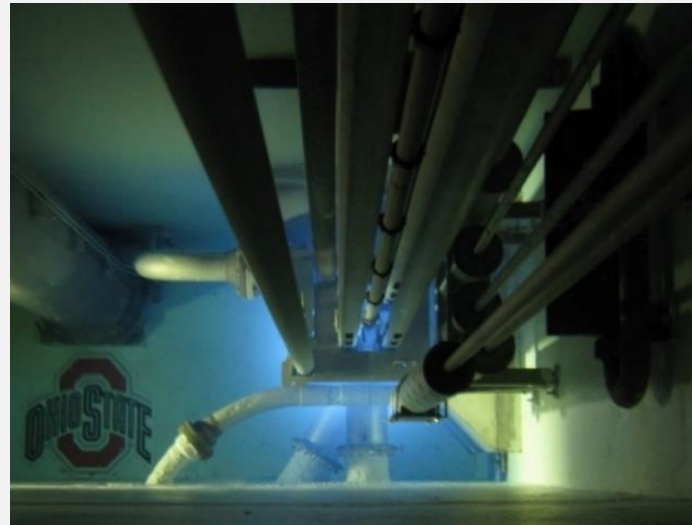
Basic Theory of Operation

Creation of an Internal Cladding in Sapphire Fiber to Produce Reduced Mode Sapphire Fiber (RMSF)

- The Ohio State University has developed a method for creating an intrinsic cladding in sapphire optical fiber
- By implanting ions into the periphery of a sapphire fiber, via the reaction below, a refractive layer forms in the sapphire with a slightly lower index of refraction that acts as an internal cladding



- The ions for implantation are created using Lithium-6 and the Ohio State Research Reactor reaction
- Using this method instead of an accelerator provides the benefit of creating large lengths of this cladded sapphire fiber in a short amount of time

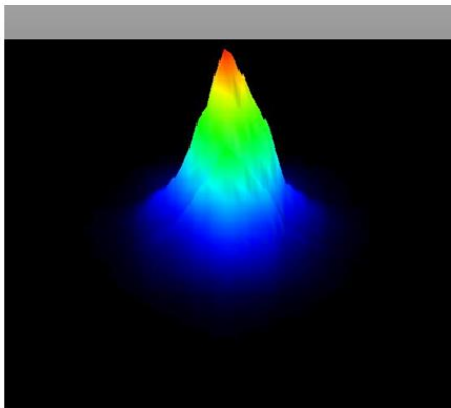
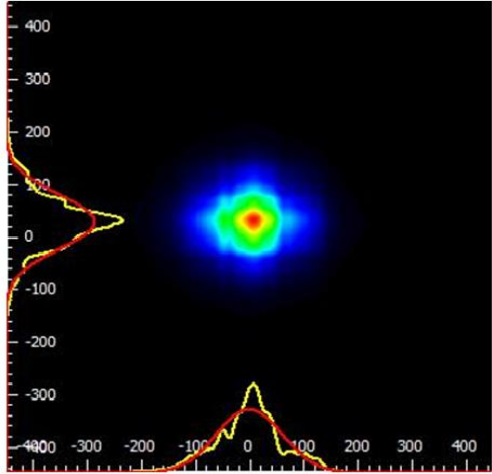


The work presented on this slide was performed at The Ohio State University prior to the current project

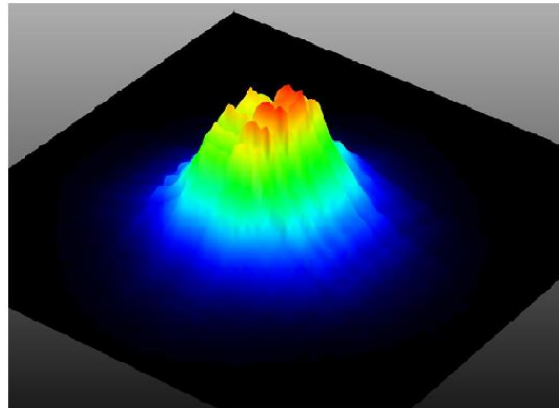
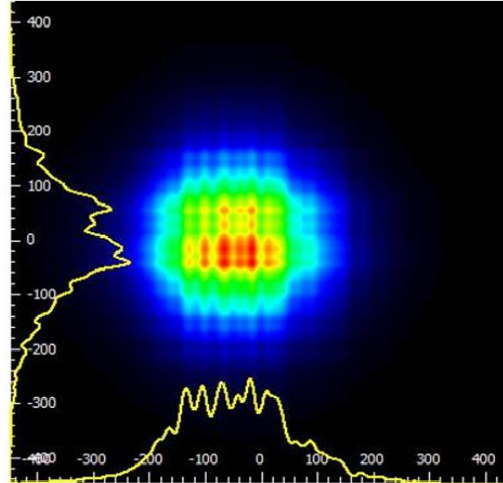
Sapphire Cladding Results

Measurements of various types of fibers using the OSU fiber transmission facility

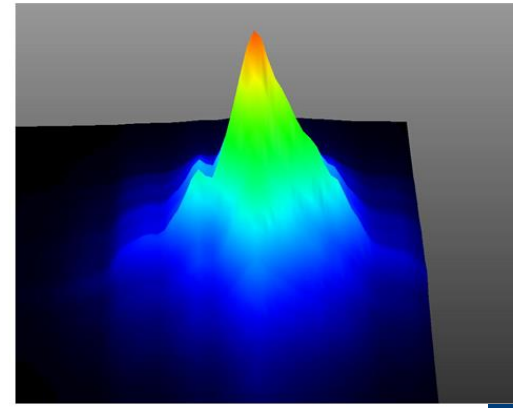
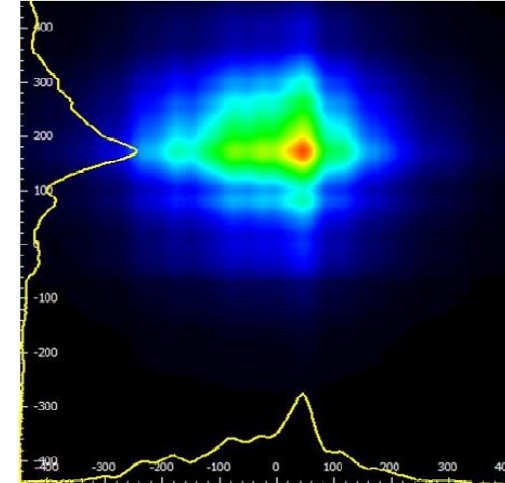
Single mode silica fiber



Unclad sapphire fiber

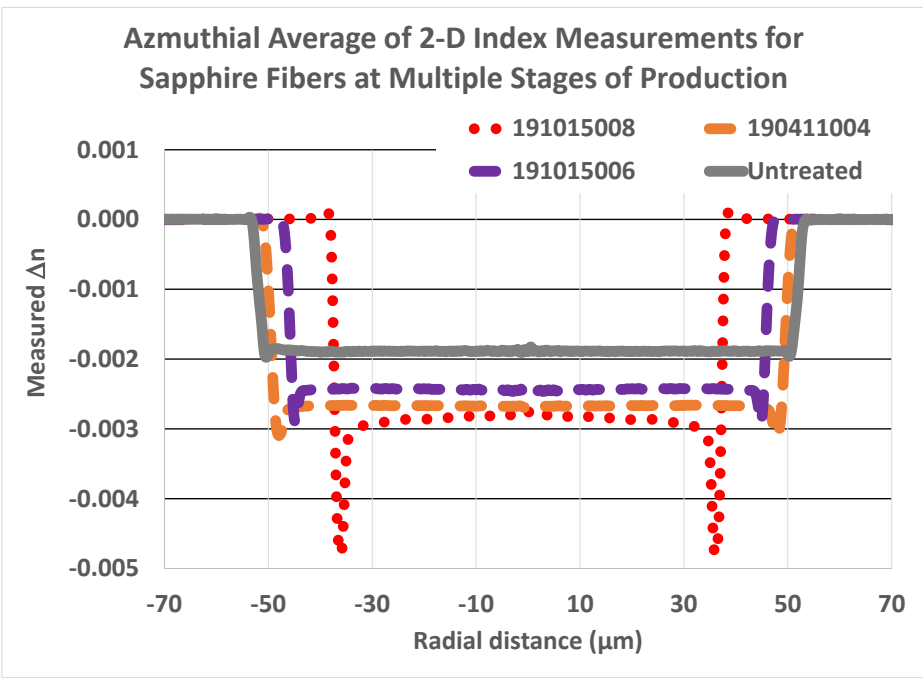
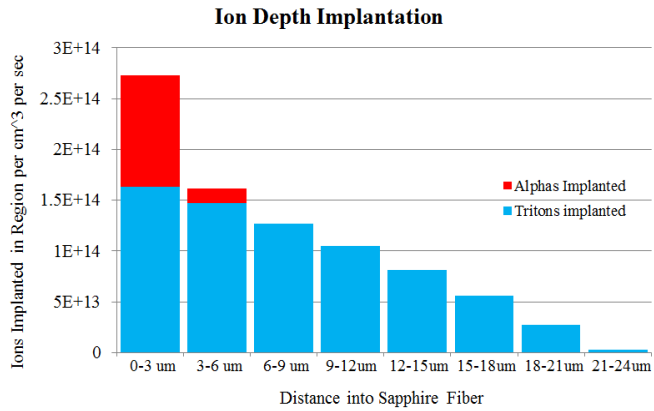
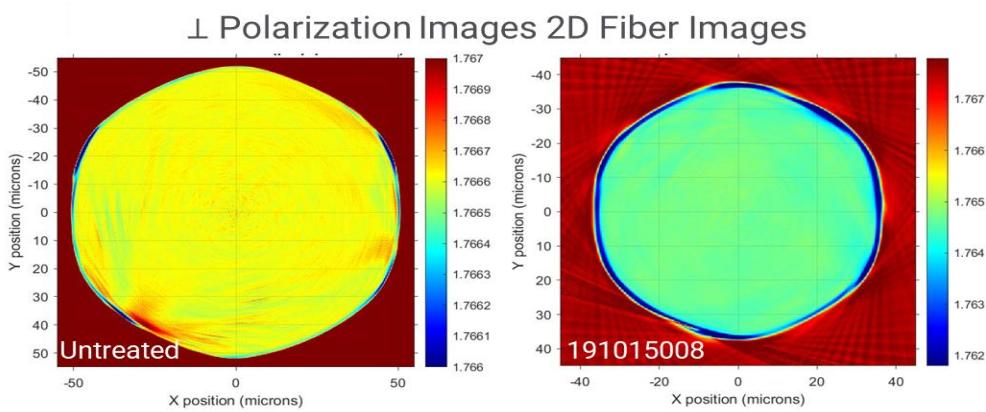


Sapphire fiber with cladding



Cladding Profile

- Index profiles have been taken of an untreated fiber and fibers that underwent ion implantation via the method of the previous slide followed by annealing process described in the table with 632.8 nm light. The index contrast will be more significant at 1550 nm.



ID#	Annealing method
Untreated	N/A
191015008	1200°C for 8 hours in 3 steps along the length
190411004	1200°C for 8 hours
191015006	1050°C for 1.5 hours followed by 1100°C for 8 hours

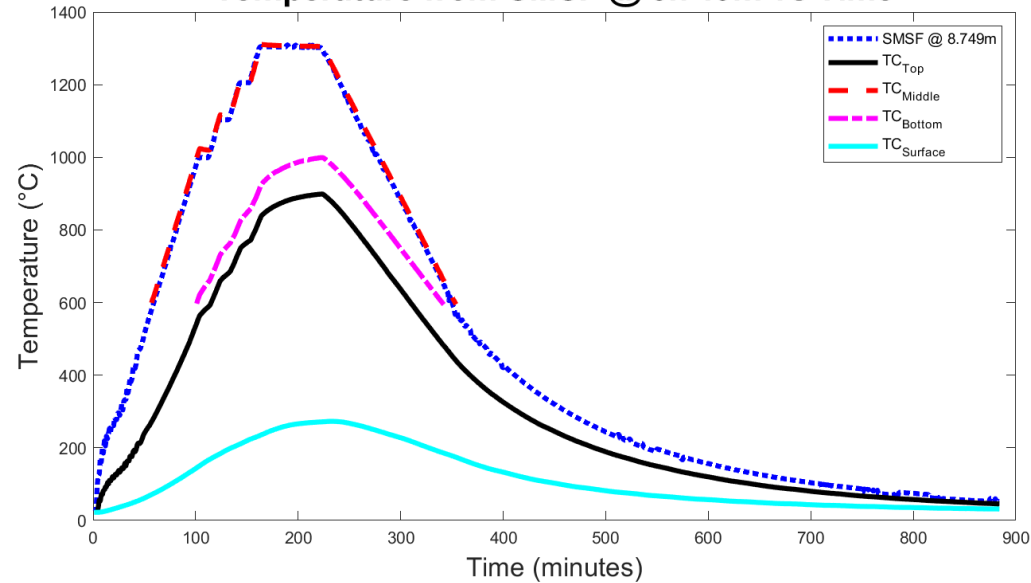
Furnace Test to 1300°C

Furnace test of Reduced Mode Sapphire Fiber (RMSF) to 1300°C interrogated with an OBR 4600



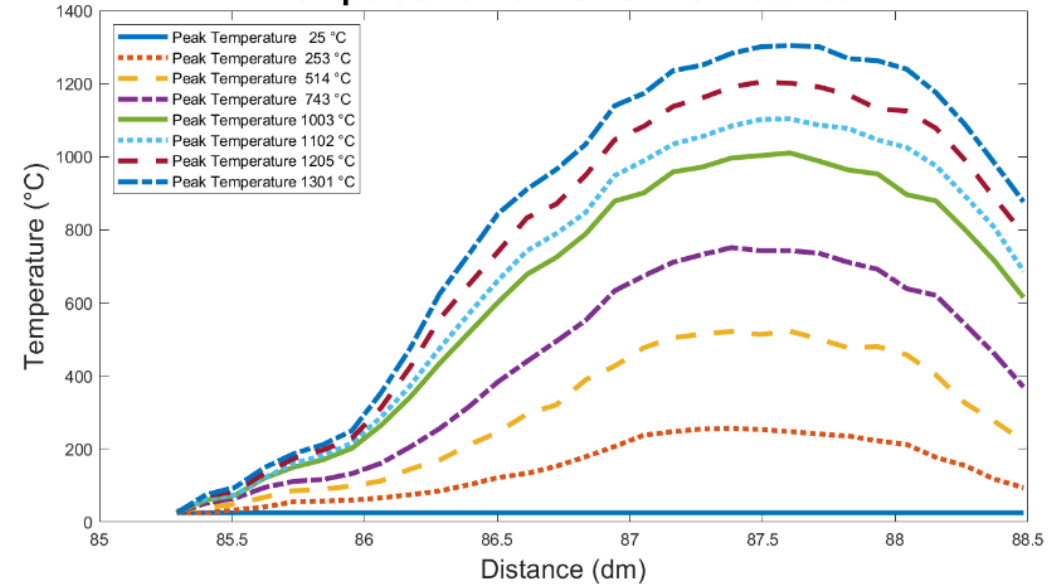
Single gage of SMSF

Temperature from SMSF @ 8.749m vs Time

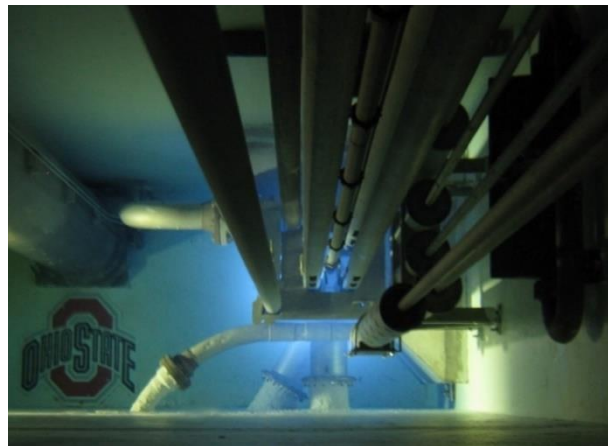
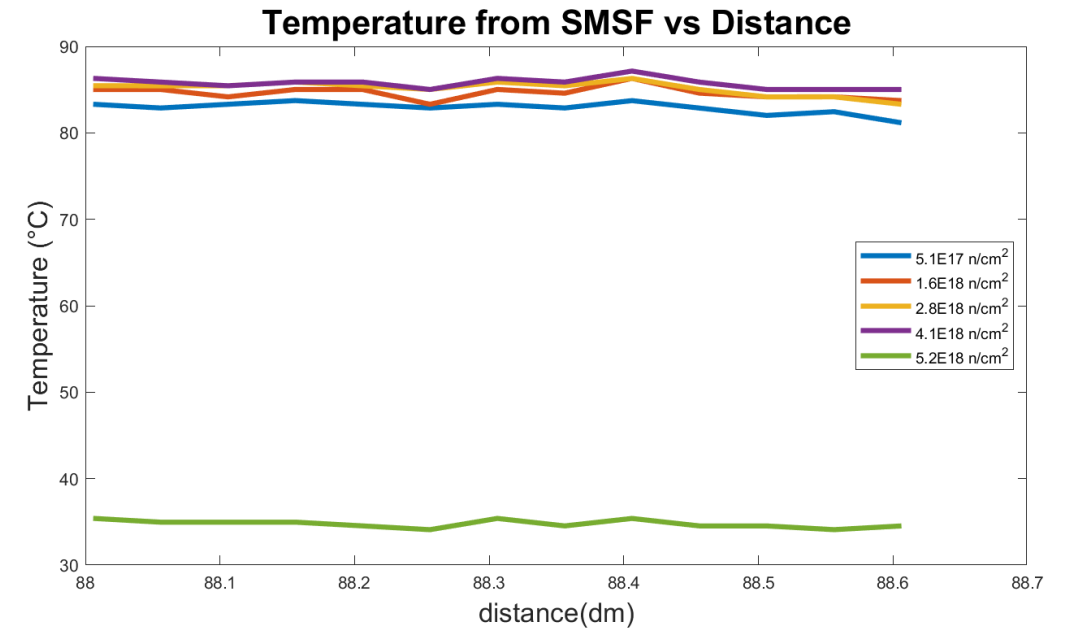
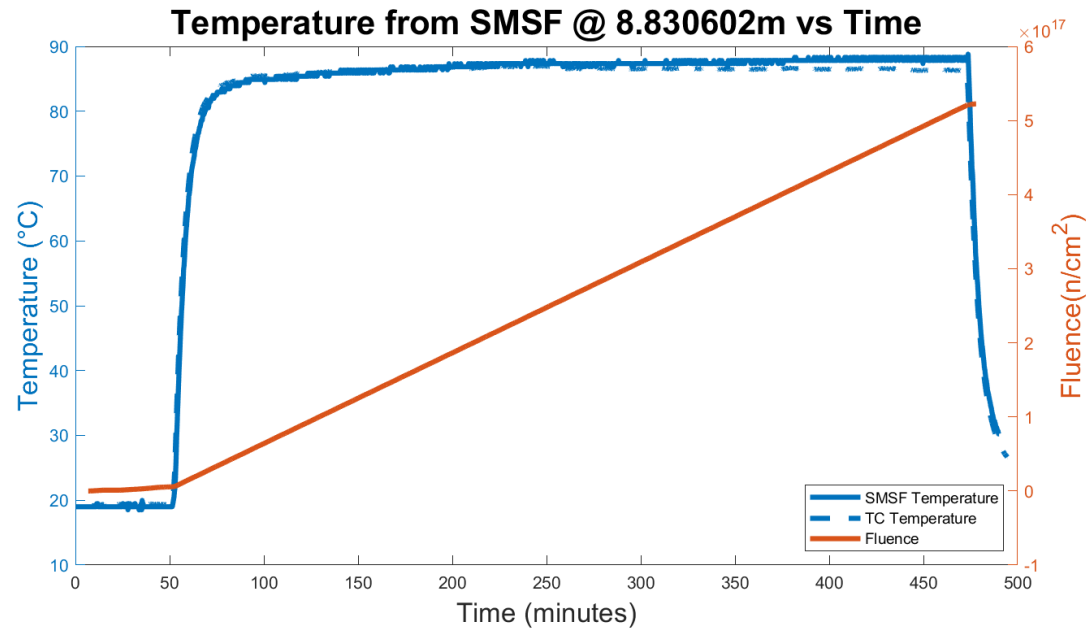


Full length SMSF at specific points in

Temperature from SMSF vs Distance

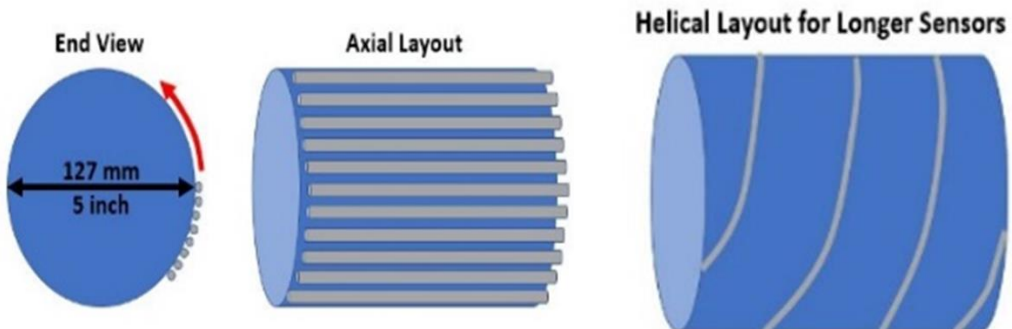


Reactor Test to Neutron Fluence $> 5 \times 10^{17}$



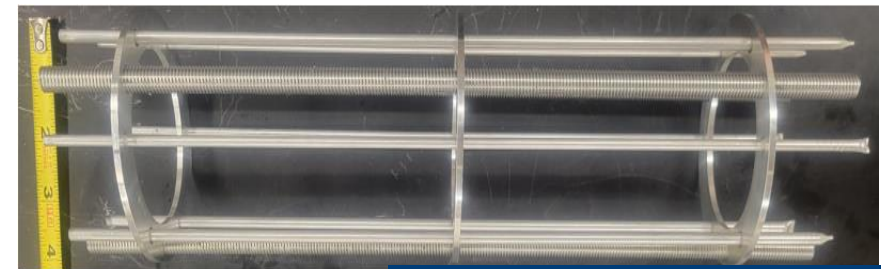
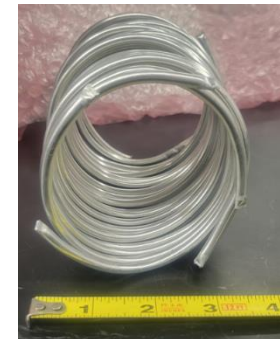
Cost reduction study and fixture design

Designs for RMSF transmutation rig



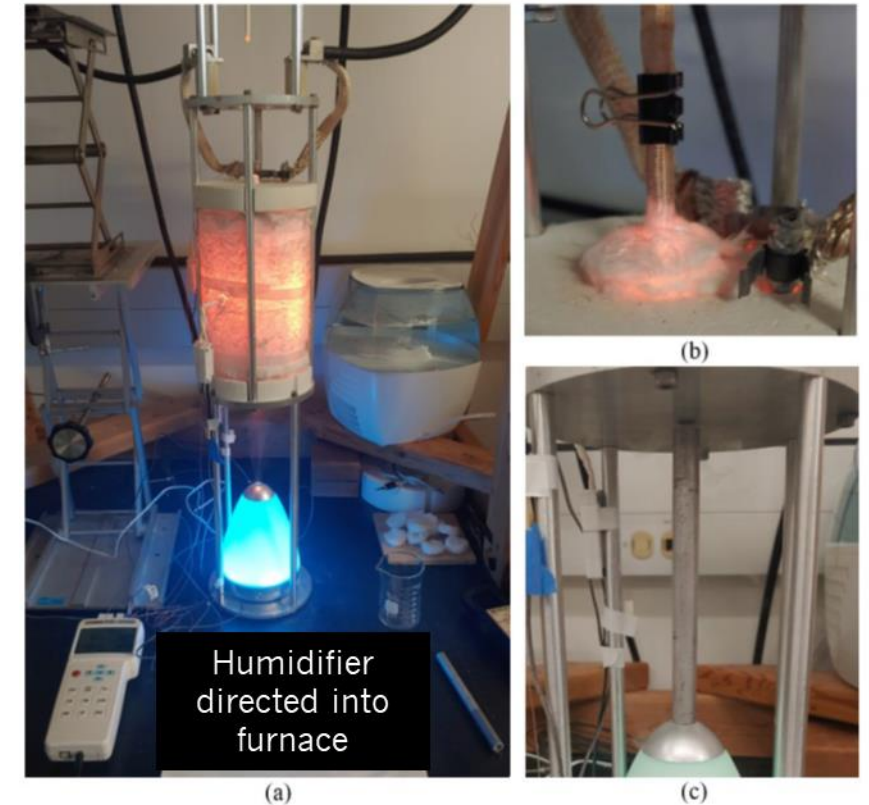
Fiber has been packed in a helical rig, shipped via UPS, returned, unpacked, and repacked with no breakage. These are the highest risk activities for the production process.

Awaiting irradiation of transmutation rigs.



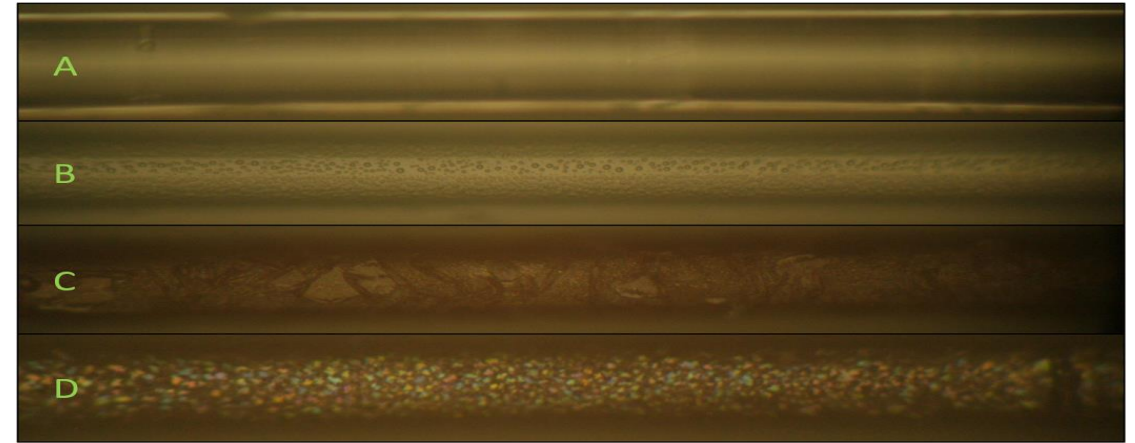
Cladding mode stripping mechanisms

- Aluminum Oxy-hydroxide added to clad surface to disrupt cladding modes
- PCT WO2021211195A1, Modification of internally clad sapphire fiber to attenuate cladding modes at high temperatures
- PCT based on work from DE-SC0019834 and DE-SC0018767



Method of Stripping Cladding Modes

- Several methods of cladding mode stripping have been presented for clad sapphire fiber in PCT WO2021211195A1
- Luna and OSU are currently pursuing formation of aluminum oxyhydroxide crystals on RMSF surface that are formed in a high temperature steam environment. The sapphire's surface has different characteristics depending stream exposure as seen in the microscopy images.



Current Status

- Luna and OSU have pushed the transmutation cost of commercial-off-the-shelf sapphire fiber to RMSF from order \$10,000/m to order \$1,000/m over the last year.
- Demonstrated performance beyond 1300 °C
- Continued production optimization is needed along with testing to the melting point of sapphire, 2050 °C